TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

2 S C 5 0 7 6

HIGH CURRENT SWITCHING APPLICATIONS

• Low Collector Saturation Voltage: VCE (sat)=0.4V (Max.)

(at $I_C = 3A$)

• High Speed Switching Time : $t_{stg} = 1.0 \mu s$ (Typ.)

• Complementary to 2SA1905

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	v_{CBO}	60	V
Collector-Emitter Voltage	v_{CEO}	50	V
Emitter-Base Voltage	$V_{ m EBO}$	5	V
Collector Current	$I_{\mathbf{C}}$	5	Α
Base Current	$I_{\mathbf{B}}$	1	Α
Collector Power Dissipation	$P_{\mathbf{C}}$	1.3	w
Junction Temperature	T_{j}	150	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C

Unit in mm

| 3.0±0.2 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 | 0.5 |

Weight: 0.55g (Typ.)

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHAR	ACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cu	ıt-off Current	I _{CBO}	$V_{CB} = 50V, I_{E} = 0$			1	μ A
Emitter Cut-off Current		I_{EBO}	$V_{EB}=5V, I_C=0$	_	_	1	μ A
Collector-En Voltage	nitter Breakdown	V (BR) CEO	$I_{C} = 10 \text{mA}, I_{B} = 0$	50	_	_	V
DC Current Gain		hFE (1) (Note)	$V_{CE}=1V$, $I_{C}=1A$	70	_	240	
		h _{FE} (2)	$V_{CE}=1V$, $I_{C}=3A$	30	_	_	
37.14	Collector-Emitter	V _{CE (sat)}	$I_{C}=3A, I_{B}=0.15A$	_	0.2	0.4	V
	Base-Emitter	V _{BE} (sat)	$I_{C}=3A, I_{B}=0.15A$	_	0.9	1.2	
Transition Frequency		$\mathbf{f_T}$	$V_{CE}=4V, I_{C}=1A$	_	120	_	MHz
Collector Output Capacitance		C_{ob}	$V_{CB} = 10V, I_E = 0, f = 1MHz$	_	80	_	pF
Switching Time	Turn-on Time	ton	20μs I _{B1} OUTPUT	_	0.1	_	μs
	Storage Time	$t_{ ext{stg}}$	I _{B1} INPUT O I _{B2} I I _{B2}	_	1.0	_	
	Fall Time	t_f	$\begin{bmatrix} I_{B1} = -\overline{I}_{B2} = 0.15A, \\ DUTY \ CYCLE \le 1\% \end{bmatrix} V_{CC} = 30V$	_	0.1	_	

(Note) : hFE (1) Classification O : 70~140, Y : 120~240

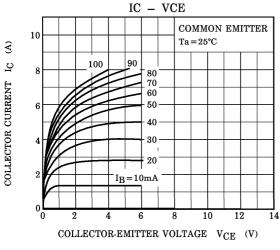
1.0

0.8

0.6

 $I_B = 10 \text{m/s}$

COLLECTOR-EMITTER VOLTAGE VCE (V)



 Λ CE - IC

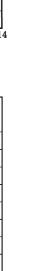
COLLECTOR CURRENT I_{C} (A)

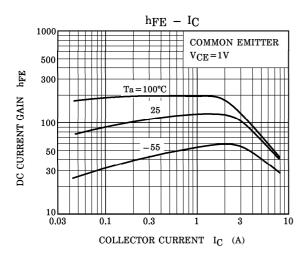
COMMON EMITTER

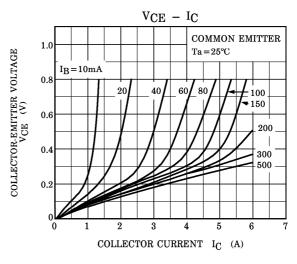
150

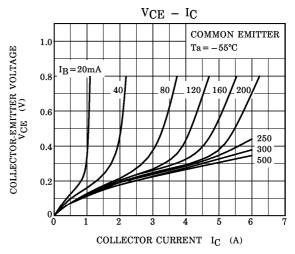
200

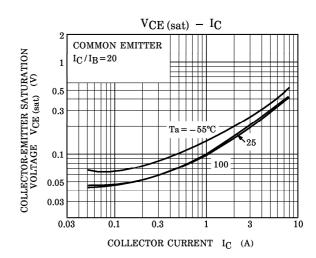
Ta = 100°C

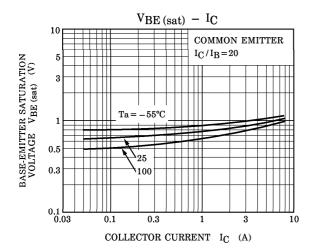


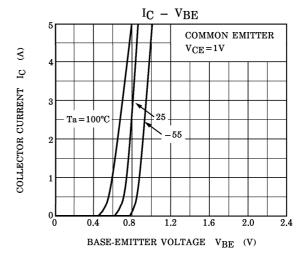


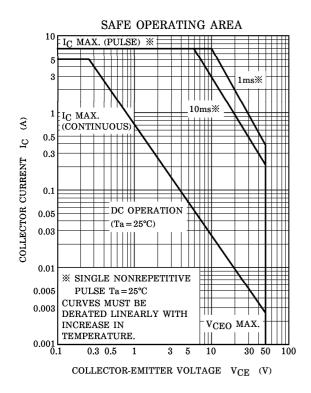












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